# Multiglass properties and magnetoelectric coupling in the uniaxial anisotropic spin-cluster-glass Fe<sub>2</sub>TiO<sub>5</sub>

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The compound Fe<sub>2</sub>TiO<sub>5</sub> (FTO) is a well-known uniaxial anisotropic spin-glass insulator with two successive glassy freezing temperatures, i.e., transverse ( $T_{TF} = 9$  K) and longitudinal ( $T_{LF} = 55$  K). In this article, we present the results of measurements of complex dielectric behavior, electric polarization as a function of temperature (T), in addition to characterization by magnetic susceptibility and heat capacity, primarily to explore magnetoelectric (ME) coupling and multiglass properties in uniaxial anisotropic spin-cluster-glass FTO. The existence of two magnetic transitions is reflected in the isothermal magnetodielectric (MD) behavior in the sense that the sign of MD is different in the T regime  $T < T_{TF}$  and  $T > T_{TF}$ . The data in addition provide evidence for the glassy dynamics of electric dipoles; interestingly, this occurs at much higher temperature ( $\sim 100-150$  K) than  $T_{LF}$ , with high remnant polarization at 10 K ( $\sim 4000 \, \mu C/m^2$ ) attributable to short-range magnetic correlations, thereby offering a route to attain ME coupling above 77 K.

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### I. INTRODUCTION

In recent literature, investigation of multiferroic properties of materials because of the presence of two or more ferroic properties in one system has proliferated. In multiferroics involving ferroelectricity and magnetism, in general strong magnetoelectric (ME) coupling is observed; that is, one can tune magnetization (M) and electric-polarization (P)or dielectric behavior by electric and magnetic fields (H), respectively [1-5]. The tunability of electric-polarization or dielectric behavior with H is highly desirable for practical applications. While ME coupling is extensively known among magnetically well-ordered materials, such studies have been recently extended to various insulating spin glasses as well [6-10], leading to the recognition of the existence of the phenomenon of "multiglass" involving glassiness of electric and magnetic states. It is of great interest to explore the nature of ME coupling in anisotropic spin-glass systems, in particular, to understand whether this behavior is different between longitudinal and transverse freezing regimes.

With this motivation, we have probed the compound Fe<sub>2</sub>TiO<sub>5</sub> (FTO) for its ME studies. This compound, crystallizing in an orthorhombic structure (*Cmcm*), is a wellknown uniaxial anisotropic insulating spin glass [11]. The physics of spin glasses with single-ion uniaxial anisotropy has been known to be interesting for the following reasons. Depending on the magnetic exchange interaction strength (J), uniaxial anisotropy (D), external H, and temperature (T), such compounds can exhibit complex magnetic phase diagrams [12,13]. For a sufficiently small value of |D|/Jratio, two successive freezing transitions, i.e., longitudinal  $(T_{LF})$  and transverse  $(T_{TF})$ , can be observed [12–14]. In the case of FTO, two such characteristic temperatures have been known, one at  $(T_{LF}=)$  55 K and the other at  $(T_{TF}=)$ 9 K [11,15–20]. These two transitions have been presumed to occur by coupling through Dzyaloshinsky-Moriya (DM)

interaction [18]. Here, on the basis of complex dielectric behavior and electric P studies, combined with the results from magnetization and heat-capacity (C) measurements, we report that (i) the behavior of ME coupling is distinctly different in different temperature regimes, i.e., above and below  $T_{TF}$ in the magnetically frozen state; (ii) the onset of dielectric anomalies and electric P occurs at a temperature (>100 K) far above  $T_{LF}$ , as though short-range magnetic correlations are adequate to favor ME coupling. This work gains importance considering that there are not many known materials in the literature exhibiting magnetism-induced electric P above 77 K, and this work demonstrates a route to attain the same; and (iii) a strong frequency (v) dependence of complex dielectric behavior near 100-150 K. In addition to frequency dependence in ac susceptibility  $(\chi)$  at  $T_{LF}$ , we infer that there is an interesting multiglass dynamics in this material.

#### **II. EXPERIMENTAL**

The polycrystalline sample of FTO has been prepared by a standard solid-state reaction method as already reported [21]. The stoichiometric amounts of Fe<sub>2</sub>O<sub>3</sub> (99.99%) and TiO<sub>2</sub> (99.99%) were sintered at 1000 °C for 24 h with intermediate grindings. Phase purity was ascertained by x-ray diffraction (XRD, Cu  $K_{\alpha}$ ). The dc magnetization measurements as a function of T (1.8–300 K) were carried out at 500 Oe for the zero-field-cooled (zfc) and field-cooled (fc) modes using a superconducting quantum interference device (SQUID, Quantum Design) magnetometer. The ac  $\chi$  was also measured at different frequencies using the same magnetometer. Complex dielectric behavior (2-300 K) with different frequencies (1-100 kHz) was obtained during warming (0.5 K/min) using E4980A LCR meter (Agilent Technologies). The T dependence of remnant P was obtained from a pyroelectric current using a Keithley 6517A electrometer. The LCR meter and electrometer were coupled with the (Quantum Design) Physical Properties Measurement System (PPMS). For pyroelectric measurement, the sample

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was cooled from high temperature to 10 K in the presence of an electric field ( $E = 740 \,\text{kV/m}$ ) and magnetic field (0 and 140 kOe). The electric field was removed at 10 K and the capacitor short circuited for 30 min to remove the stray charges (if present). The charge vs time behavior was recorded for more than 1 h to insure the stability of charge with time before starting temperature-dependent measurements. The similar symmetric results were obtained after reversing the direction of the poling electric field, i.e.,  $E = -740 \,\text{kV/m}$ . The temperature-dependent heat-capacity measurements were performed using PPMS.

## **III. RESULTS AND DISCUSSION**

Figure 1 shows the Rietveld-refined (FULLPROF suite) XRD pattern of FTO. As mentioned earlier, this compound crystallizes in (pseudobrookite) orthorhombic structure (Cmcm). In this structure, there are four formula units per unit cell. The refined lattice parameters are found to be consistent with the earlier report [21]. On the basis of absence of (112) peak intensity in the powder neutron diffraction data, Atzmony et al. [11] concluded the absence of long-range crystallographic ordering of Fe<sup>3+</sup> and Ti<sup>4+</sup> at 4c and 8f sites, respectively. On the contrary, Guo et al. claims that this system is neither fully ordered nor completely random [21]. Therefore, in the case of partial disorder, one can observe the (112) peak with some finite intensity, even in the XRD pattern. In the inset of Fig. 1, the presence of (112) peak is demonstrated, which clearly confirms the partially ordered nature of the FTO specimen under investigation.

We now present the results of ac and dc M(T) as well as C(T) measurements to bring out the features due to magnetic ordering. Since magnetization behavior has been reported in depth at several places in the past literature [11,15–20], the discussions of the results are made in brief for the sake of completeness to enable the readers to understand the complex dielectric results. The zfc dc M(T) curve obtained while warming in a field of 500 Oe, shown in Fig. 2(a), reveals two peaks, one at  $T_{LF} = 55$  K and the other at  $T_{TF} = 9$  K, in



FIG. 1. (Color online) Rietveld refinement of an x-ray diffraction pattern of  $Fe_2TiO_5$  at room temperature.

accordance with the earlier results on single crystal [11,17,18]. It is worth mentioning that the data on our polycrystalline sample shows more prominent features at  $T_{LF}$  and  $T_{TF}$  when compared with the past literature on polycrystals, which indicates relatively more crystallographic ordering in our sample. There is a bifurcation of zfc-fc curves near 55 K, which is one of the characteristics of spin glasses [22]. There are



FIG. 2. (Color online) For Fe<sub>2</sub>TiO<sub>5</sub>, temperature dependence of (a) dc magnetization measured in zfc and fc mode in 500 Oe. The lower inset shows  $M_{zfc ref}$  and  $M_{zfc w}$  curves obtained with 4 h waiting at 40 K as described in the text; the upper inset shows  $\chi^{-1}$  vs *T* up to 310 K. (b) Real part of ac susceptibility measured with  $\nu = 0.13$  and 13 Hz; inset shows ac  $\chi$  in an expanded scale near  $T_{LF}$ . (c) Heat capacity divided by temperature as a function of temperature; in the inset, the curve is shown in an expanded form in the *T* range 100–200 K.

corresponding features in ac  $\chi(T)$  data as well [see Fig. 2(b)]. In addition, the real part  $(\chi')$  of ac  $\chi$  exhibits an observable shift of the cusp at  $T_{LF}$  with increasing  $\nu$ , as observed by Tholence et al. [20] on single crystals. We have also obtained a signature of glassy magnetic state from other results, namely, "memory" experiments [22,23]. While the zfc curve (called  $M_{\rm zfc ref}$ ) described above was obtained in the sweep mode with negligible waiting time at each measurement temperature, an additional zfc curve was obtained in the following manner: the sample was cooled from 200 K to a waiting temperature  $(T_w=)$  40 K, allowed to wait there for time  $(t_w=)$  4 h, and then cooled to 1.8 K, following which the data was collected during warming with the same experimental parameters as mentioned for the  $M_{\rm zfc \ ref}$  curve; the curve thus obtained is labeled as  $M_{zfc}$  w. These curves are also shown in the bottom inset of Fig. 2(a). It is clear from the inset that there is a distinct dip at the waiting temperature, i.e., at 40 K. This kind of "local dip" (known as a "memory effect") was also observed at other waiting temperatures below  $T_{LF}$  (not shown here) and the depth of the dip was found to increase with increasing  $t_{\rm w}$ . The above-described results firmly establish the spin-glass nature of this system [22,23] below  $T_{LF}$ .

Further inference for the glassy nature of the magnetic ordering is made from the C(T) curve, shown in Fig. 2(c) in the form of C(T)/T vs T; as expected, the  $\lambda$  anomaly is absent near 55 K, and even near 9 K, though a weak drop is observed around 9 K. A notable feature in the C(T)/T plot is that there is a broad maximum centered at around 150 K, which indicates that there is an anomaly around this temperature. The overall behavior of C(T) in this temperature range is dominated by lattice and magnetic contributions. Similar C(T) behavior was also reported for other systems, e.g., in CuMn [24] and  $Ca_3Co_2O_6$  [25], and attributed to short-range order. At this stage, an isostructural nonmagnetic reference compound is not available to separate out precisely the lattice and magnetic contributions. One possible explanation can be given in terms of short-range magnetic correlations extending to such a high temperature range. In support of this interpretation, the plot of  $\chi^{-1}$  vs T [see inset of Fig. 2(a)] is found to be nonlinear in a wide T range in the paramagnetic state, in agreement with a previous report [11]. Alternatively, this can be attributed to some other broad transition as that evidenced in this article (see below). In any case, this observation is quite important to one of the main conclusions from magnetic, dielectric, and remnant P behavior.

We now address dielectric behavior. Figures 3(a) and 3(b) show the temperature-dependent complex dielectric permittivity obtained with different frequencies (1–100 kHz). It is known that this material is highly insulating at low T, which is the prerequisite for the intrinsic nature of dielectric behavior. Consistent with this, the value of  $\tan \delta$  is also very small. There is no visible sharp change in dielectric constant ( $\varepsilon'$ ) as well as in  $\tan \delta$  at  $T_{LF}$  (=55 K), though a feeble and gradual fall is observed near  $T_{TF}$  (=9 K) and can be seen more clearly in Fig. 3(c). Another observation we have made is that there is a strong frequency-dependent shoulder in the range of 100–150 K (much higher than  $T_{LF}$ ). There is a continuous increase in dielectric constant well above this temperature range. We attribute this to a small increase in electrical conduction known commonly in the literature, rather



FIG. 3. (Color online) Panels (a) and (b) show temperature dependence of the real part ( $\varepsilon'$ ) of the dielectric constant and tan $\delta$  for Fe<sub>2</sub>TiO<sub>5</sub> at different frequencies. The arrows indicate the direction in which curves move with increasing frequency; inset in (b) illustrates the memory effect at 30 K at 50 kHz after waiting at 30 K for 15 h. Panel (c) illustrates the first derivative of  $\varepsilon'$  vs *T* at two frequencies; inset shows power-law dependence of the peak in  $d(\tan\delta)/dT$ , as described in the text. Panel (d) shows isothermal magnetodielectric data  $MD[=(\varepsilon'_H - \varepsilon'_{H=0})/\varepsilon'_{H=0}]$  at different temperatures measured at 100 kHz; inset shows the coefficient of quadratic term ( $\beta_2$ ) as a function of temperature. (For more details about fitting, see the text.)

than attributing it to a global ferroelectric transition setting at such temperatures. The point of central emphasis is that this dipolar cluster-glass-like behavior actually sets in well above  $T_{LF}$ . This is clearly seen in the derivative plots, shown for two frequencies in Fig. 3(c). The peak temperatures  $(T_m)$  of the derivatives are found to obey the power law behavior, i.e.,  $v = v_0 (T_m/T_g - 1)^{zv}$ . This is demonstrated in the inset of Fig. 3(c), and  $T_m$  was obtained from  $d(\tan \delta)/dT$  plots at different frequencies. The values of fitting parameters  $T_g$ , zv, and  $\tau_0 (= 1/2\pi v_0)$  are 72 K, 4.7 and  $1.7 \times 10^{-7}$ s, respectively. The observed frequency dependence is a typical characteristic of dipolar cluster glass [26]. In order to explore additional characteristics of the electric-glassy state, we have performed "memory" experiments at 30 K after waiting for 15 h at 50 kHz (as described above for spin-glass freezing). There is a weak but visible dip in  $\Delta \varepsilon'$  at the waiting temperature, i.e., at 30 K. This is presented in the inset in panel (b) of Fig. 3; here  $\Delta \varepsilon'$  is the difference between  $\varepsilon'_{\rm ref}$  and  $\varepsilon'_{\rm wait},$  as defined for the corresponding magnetization data. The depth of the dip is very small, presumably because such memory effects are broadened due to the chemical disorder well known for this material. The observed frequency dependence may reflect slow electric-dipole dynamics, which are yet to be unraveled. The frequency dependencies in both ac susceptibility and complex dielectric properties are scarce for stoichiometric (that is, undoped) compounds, barring a few exceptions [27,28]. The demonstrations of distinct memory effect both in magnetic and dielectric studies support the multiglass behavior of FTO, as was first observed in the ME multiglass  $SrTi_{0.98}Mn_{0.02}O_3$  [6]. In addition, we have measured  $\varepsilon'$  vs T at different magnetic fields up to 140 kOe, but there is no change in these dielectric anomalies (not shown here). As the temperature is lowered, similar to magnetization and heat-capacity results, the anomaly at  $T_{TF}$  is also observed in dielectric results and can be seen more clearly in Fig. 3(c).

In order to address whether there is any difference in the magnetodielectric behavior across these magnetic transitions,  $\varepsilon'$  was measured with 100 kHz as a function of H at various temperatures, the results of which are shown in Fig. 3(d) in the form of *MD* vs *H*, where  $MD = [\{\varepsilon'(H) - \varepsilon'(0)\}/\varepsilon'(0)]$ . The magnitude of MD is comparable with the reported value for other well-known ME materials, i.e., chromite spinel [29]. These results clearly reveal that there are qualitative changes in the behavior as the temperature is lowered. In particular, the sign of *MD* is different for  $T < T_{TF}$  and  $T > T_{TF}$  prominently seen above 50 kOe. It is possible that the expected anomaly near  $T_{LF}$  (in the plots as a function of T) could be broadened due to its sensitivities to some degree of crystallographic disorder (intrinsic to this material due to partial disorder of  $Fe^{3+}$  and  $Ti^{4+}$  at 8 f and 4c sites). The different sign of MD at a different T regime is generally scarce, barring exceptions like in the case of BiMn<sub>7</sub>O<sub>12</sub>, hexagonal TbMnO<sub>3</sub>, and  $Ca_3CoMnO_6$  [30–32]. The observed *MD* vs *H* behavior suggests the presence of a higher-order ME coupling effect in this system (mostly quadratic at higher H). The sign of MDdepends on the temperature and magnetic field and can be explained by using the simple phenomenological model given by Katsufuji et al. [33]



FIG. 4. (Color online) (a) Temperature dependence of remnant polarization (*P*) at 0 and 140 kOe (for details see text); pyroelectric current is also shown in the inset. (b) Derivative of dc  $\chi$  measured at 500 Oe; inset shows  $d^2\chi/dT^2$  vs *T* behavior.

where  $\langle S_i \cdot S_j \rangle_H$  is the spin-pair correlation of neighboring spins at a particular applied *H*. This value is negative in the case of antiferromagnetic ordering and positive for ferromagnetic or paramagnetic regime. We fitted the *MD* results by using the combination of linear and quadratic terms of *H*, i.e., *MD* ~  $(\beta_1 H + \beta_2 H^2)$ , as reported earlier [31,32]. The coefficient of fitting parameter of the quadratic term, i.e.,  $\beta_2$ , is plotted as a function of temperature in the inset of panel (d) of Fig. 3. It can be clearly seen from this inset that the sign of  $\beta_2$  is changing at  $T_{TF}$ , which shows that the sign of ME coupling is different at  $T < T_{TF}$  and  $T > T_{TF}$ .

In order to further address ME coupling and electric P, we have studied remnant P behavior, as described in the Experimental Results section. The results are presented in Fig. 4(a). The pyroelectric current is also shown in the inset of Fig. 4(a). The key finding is that the electric *P* sets in at a very high temperature (>150 K) above  $T_{LF}$ . The P changes slowly with increasing T until  $\sim 120$  K, and then decreases sharply, following which it becomes temperature independent at higher T. The sign of P is changed by reversing the poling electric field. The value of P above 150 K changes continuously, which shows that there is no first-order phase transition across this temperature regime. The value of P also changes with the application of H (for an application of 140 kOe), as shown in the same figure, which proves the existence of ME coupling. Such ME coupling above 77 K is observed in CuO [34] and a few other systems also [27,35]. The remnant P in the absence of a magnetic field at 10 K is  $\sim 4000 \,\mu\text{C/m}^2$ 

$$\varepsilon' = \varepsilon'_0 (1 + \alpha < S_i \cdot S_j >_H)$$

and is close to the value reported for CaBaCo<sub>4</sub>O<sub>7</sub> single crystal [36]. Our results show the qualitative evidence of electric *P* at 740 kV/m poling electric field, and quantitatively, it can be higher at higher poling fields. The FTO structure consists of two noncentrosymmetric coordinations, i.e., FeO<sub>6</sub> and TiO<sub>6</sub>, and the FeO<sub>6</sub> octahedron is more distorted than TiO<sub>6</sub> octahedra [18]. These results indicate the polar behavior of FTO and its tunability with external *H*.

From the above results, it is thus evident that there is a strong ME coupling, even much greater than  $T_{LF}$ . The question arises as to what is the origin of this feature. We attribute it to the short-range magnetic correlations. In support of this proposal, we refer to the quasielastic neutron scattering [37] and Mössbauer spectroscopy (MS) [19] results, which show the presence of short-range magnetic correlations well above  $T_{LF}$ . In conjunction with this, the absence of Curie-Weiss behavior in susceptibility [see upper inset of Fig. 2(a)],  $d\chi/dT$  vs T and  $d^2\chi/dT^2$  vs T in Fig. 4(b) and its inset, respectively, further establishes the existence of short-range magnetic correlations well above  $T_{LF}$ , i.e., at around 150 K. Furthermore, the presence of short-range correlations up to 150 K can be inferred from Fig. 4(b). Around 150 K one can see the change in slope in  $d\chi/dT$  vs T as well as in  $d^2\chi/dT^2$  vs T [see inset of Fig. 4(b)]. The broad peak in C(T)/T vs T presented in this article is either in support of this short-range magnetic correlations and/or a direct consequence of the local polar behavior in this temperature region. The onset of P [see Fig. 4(a)] appears at higher temperature than the peak in  $d\varepsilon'/dT$  vs T [Fig. 3(c)]. FTO is a disordered material and its frequency dependence dielectric permittivity shows dipolar cluster-glass-like behavior; hence P can exist well above the peak in dielectric permittivity due to the nucleation of polar-nano regions (PNR). The occurrence of PNR above the dielectric peak has been known for relaxor ferroelectrics [26]. Similar to our results, a tail in P above the dielectric peak is also observed in Mn-doped SrTiO<sub>3</sub> [38].

Such a behavior has been reviewed in the article by Cross [39]. In short, we conclude that this compound serves as a rare example among oxides in which ME coupling can arise from short-range magnetic correlations, though very recently ME coupling and P were reported in the paramagnetic regime in a metallorganic framework  $[(CH_3)_2NH_2]Mn(HCOO)_3$  [40]. Similar findings have been reported in a spin-chain material,  $Ca_3Co_2O_6$  [27]. The remnant P is high and comparable with type-I multiferroics. This high polarization value could not be solely due to magnetic short-range correlations but can be related to local polar transition also. A high-resolution low-temperature x-ray diffraction is worthwhile to throw some light on the exact microscopic origin of the observed P results. Finally, it should be noted that the value of  $tan\delta$  is very small, up to 150 K, i.e.,  $tan\delta = 0.04$ , and the phase angle between current and voltage at 150 K turns out to be about  $-88^{\circ}$ , which is very close to the value for an ideal capacitor. Hence, the observed ME coupling in this material is due to its intrinsic properties rather than extrinsic effects, such as magnetoresistance [41], grain boundaries, etc.

#### **IV. CONCLUSION**

To summarize, we have reported the evidence for multiglass properties and ME coupling in an anisotropic spin glass,  $Fe_2TiO_5$ . The sign of magnetodielectric changes as the sample is cooled from longitudinal freezing temperatures across transverse freezing temperatures. A key finding is that ME coupling is found to set in at a temperature far above the longitudinal freezing temperature. Our results demonstrate that short-range magnetic correlations also can trigger ME coupling. It should be noted that such correlations yield spontaneous electric *P* at higher temperatures far above 77 K, thereby offering a route to identify materials for applications involving coupled multiple phenomena. This work gains importance considering the current interest in identifying ME materials above 77 K.

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